Full Bridge Power Amplifier

FEATURES

- Dual Power Operational Amplifiers
- ±2A Output Current Guaranteed
- Precision Current Sense Amplifier
- Two Supply Monitoring Inputs
- Parking Function and Under-Voltage Lockout
- Safe Operating Area Protection
- 3V to 35V Operation

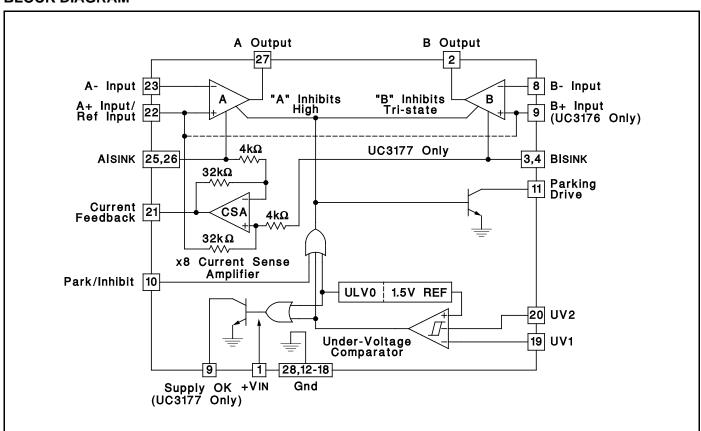
DESCRIPTION

The UC3176/7 family of full bridge power amplifiers is rated for a continuous output current of 2A. Intended for use in demanding servo applications such as disk head positioning, the onboard current sense amplifier can be used to obtain precision control of load current, or where voltage mode drive is required, a standard voltage feedback scheme can be used. Output stage protection includes foldback current limiting and thermal shutdown, resulting in a very rugged device.

Auxiliary functions on this device include a dual input under-voltage comparator that can be programmed to respond to low voltage conditions on two independent supplies. In response to an under-voltage condition the power Op-Amps are inhibited and a high current, 100mA, open collector drive output is activated. A separate Park/Inhibit command input.

The devices are operational over a 3V to 35V supply range. Internal under-voltage lockout provides predictable power-up and power-down characteristics.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS (Note 1)

ADOCEOTE MAXIMOM KATINGO (NOIC 1)
Input Supply voltage, (+VIN)40V
Park/Inhibit, UV1 and UV2 inputs (zener clamped)
Maximum forced voltage0.3V to 10V
Maximum forced current ±10mA
Other Input Voltages0.3V to +ViN
Alsınk and Blsınk Voltages0.3V to 6V
Open Collector Output Voltages 40V
A and B Output Currents (Continuous)
Source Internally Limited
Sink
Total Supply Current (Continuous)4A
Parking Drive Output Current (Continuous) 200mA
Supply OK Output Current, UC3177 (Continuous) 30mA
Operating Junction Temperature55°C to +150°C
Power Dissipation at TC = +75°C
QP package
Storage Temperature65°C to +150°C
Note 1: Unless otherwise indicated, voltages are reference to
ground and currents are positive into, negative out of, the
specified terminals.

THERMAL DATA

QP package:

Thermal Resistance Junction to Leads, θ_{JL} 15°C/W Thermal Resistance Junction to Ambient, θ_{JA} 50°C/W

CONNECTION DIAGRAM

PLCC-28 (Top View) QP Package

4 3 2	1 28 27 26
5	
Ī 6	24
d 7	23
₫8	22
∮9	21
[10	20
[11	. 19
12 13 14	15 16 17 18

PACKAGE PIN FUNCTION			
FUNCTION	PIN		
+VIN	1		
B Output	2		
BISINK(Sense)	3		
BISINK	4		
N/C	5-7		
B- Input	8		
*	9		
Park/Inhibit	10		
Parking Drive	11		
Gnd (Heat Flow Pins)	12-18		
UV1	19		
UV2	20		
Current Feedback	21		
A+ Input	22		
A- Input	23		
N/C	24		
Alsınk	25		
Alsınk(Sense)	26		
A Output	27		
Gnd	28		
*Pin 9: 11C3176 B+ Inc	out.		

*Pin 9: UC3176, B+ Input UC3177, Supply OK

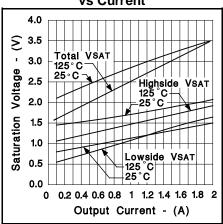
ELECTRICAL CHARACTERISTICS: Unless otherwise stated, specifications hold for TA = 0 to 70°C, +VIN = 12V, TA = TJ.

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Supply			•	•	-
Supply Current	+VIN = 12V		18	25	mA
	+VIN = 35V		21	30	mA
UVOL Threshold	+VIN low to high		2.8	3.0	V
	Threshold Hysteresis		220	300	mV
Power, Amplifier, A and B					
Input Offset Voltage	VCM = 6V, VOUT = 6V			8	mV
Input Bias Current	VCM = 6V, Except A+ Input	-500	-100		nA
Input Bias Current at A+/Reference Input	(A+/Ref - BISINK)/36kohms; TJ = 25°C	23	28	35	μΑ/V
Input Offset Current B Amp (UC3176 Only)	VCM = 6V			200	nA
CMRR	Vcm = 1 to 33V, +Vin =35V, Vout = 6V	70	100		dB
PSRR	+VIN = 5 to 35V, $VCM = 2.5V$	70	100		dB
Large Signal Voltage Gain	VOUT = $3V$, $w/100T = 1A$ to $VOUT = 9V$, $w/100T = -1A$	1.5	4		V/mV
Thermal Feedback	+VIN = 20V, Pd = 20W at opposite output		25	200	μV/W
Saturation Voltage	IOUT = -2A, High Side, TJ = 25°		1.9		V
	Clout = 2A, Low Side, T _J = 25°C		1.6		V
	Total Vsat at 2A, TJ = 25°C		3.5	3.7	V
Unity Gain Bandwidth			1		MHz
Slew Rate			1		V/μs
Differential IOUT Sense Error Current	IOUT(A) = -IOUT(B), /IOUT/- /AISINK - BISINK/				
in Bridge Configuration	IOUT ≤200mA		3.0	6.0	mA
	IOUT ≤ 2A		5.0	10	mA
High Side Current Limiting	=VIN - VOUT < 12V		-2.7	-2.0	Α

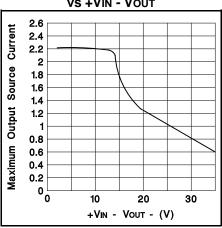
ELECTRICAL CHARACTERISTICS: Unless otherwise stated, specifications hold for Ta = 0 to 70°C, +VIN = 12V, Ta = TJ.

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Current Sense Amplifier			•	•	•
Input Offset Voltage	Vcm = 0V, A+/Ref at 6V			3	mV
	Ref = 2V to 20V, +VIN = 35, change with Ref				
	input voltage			600	μV/V
Thermal Gradient Sensitivity	+VIN = 20V, Ref = 10V Pd = 20W @ A or B				
	output		5.0	75	μV/W
PSRR	Ref = $2.5V$, $+VIN = 5$ to $35V$	70	100		dB
Gain	/Alsınk - Blsınk/ $\leq 0.5V$	7.8	8	8.1	V/V
Slew Rate			2		V/μS
3dB Bandwidth			1		MHz
Max Output Current	ISOURCE = +VIN - VOUT = 0.5V	2.5	3.5		mA
Output Saturation Voltage	ISOURCE = 1.5mA, High Side		0.15	0.30	V
	ISINK = 5mA, Low Side		1.4	1.7	V
Under-Voltage Comparator					
Threshold Voltage	Low to High, other input at 5V	1.44	1.50	1.56	V
	Threshold Hysteresis	50	70	80	mV
Input Current	Input = 2V, other input at 5V	-2	05		μΑ
Supply OK V _{SAT} (UC3177 Only)	IOUT = 5mA			0.45	V
Supply OK Leakage (UC3177 Only)	Vout = 35V			5	μΑ
Park/Inhibit					
Park/Inhibit Thl'd		1.1	1.3	1.7	V
Park/Inhibit Input Current	At threshold		60	100	μΑ
Parking Drive Saturation Voltage	I _{OUT} = 100mA		0.3	0.7	V
Parking Drive Leakage	V _{OUT} = 35V			15	μΑ
Thermal Shutdown					
Shutdown Temperature			165		°C

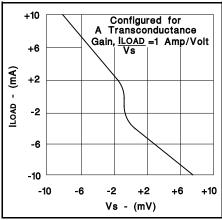
Output Saturation Voltage vs Current



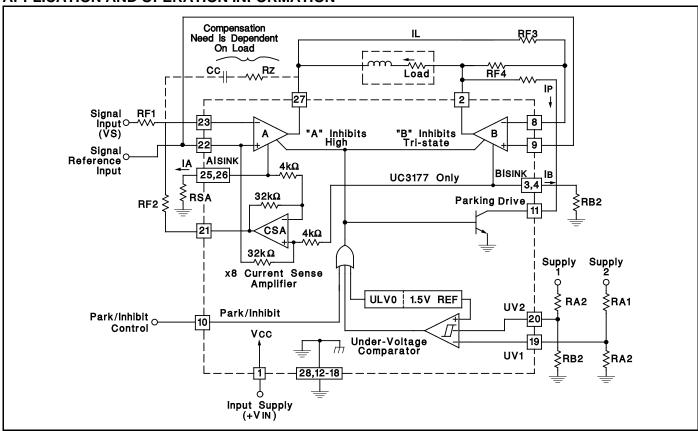
Maximum Source Current vs +VIN - Vout



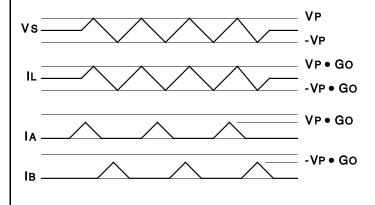
Crossover Current Error Characteristic



APPLICATION AND OPERATION INFORMATION



WAVEFORMS FOR ABOVE APPLICATION



DESIGN EQUATIONS

Transconductance (Go) = $\frac{IL}{VS} = \frac{RF2}{RF1} \times \left(\frac{1}{8Rs}\right)$

with: RSA = RSB and RF3 = RF4

Parking Current (IP) = $\frac{V_{IN} - 1.5}{R_{P} + R_{L}}$

where: RL = load resistance

Under-Voltage Thresholds, at Supplies
High to Low Threshold, (VLH) = 1.425 (RA + RB)/RB
Low to High Threshold, (VHL) = 1.5 (RA + RB)/RB

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1999, Texas Instruments Incorporated